

SiC Schottky Barrier Diode

V_R	650V		
I _F	8A		
Q_{C}	13nC		

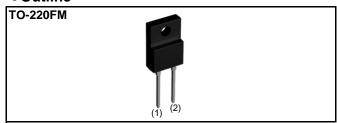
● Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

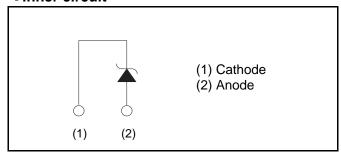
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS208AM

● Absolute maximum ratings (Tj = 25°C)

Symbol	Value	Unit	
V_{RM}	650	V	
V _R	650	V	
I _F	8* ¹	Α	
	31* ²	Α	
I _{FSM}	118* ³	Α	
	25* ⁴	А	
I _{FRM}	23* ⁵	А	
P _D	34* ⁶	W	
Tj	175	°C	
Tstg	-55 to +175	°C	
	V _{RM} V _R I _F I _{FSM} I _{FRM} P _D Tj	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	

^{*1} Tc=101°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C

^{*4} PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.16mA	600	-	-	V
Forward voltage	V _F	I _F =8A,Tj=25°C	-	1.35	1.55	V
		I _F =8A,Tj=150°C	-	1.55	-	V
		I _F =8A,Tj=175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,Tj=25°C	-	1.6	160	μΑ
		V _R =600V,Tj=150°C	-	24	-	μΑ
		V _R =600V,Tj=175°C	-	56	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	291	-	pF
		V _R =600V,f=1MHz	-	30	-	pF
Total capacitive charge	Qc	V _R =400V,di/dt=350A/μs	-	13	-	nC
Switching time	tc	V _R =400V,di/dt=350A/μs	-	13	-	ns

Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	3.9	4.4	°C/W

• Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

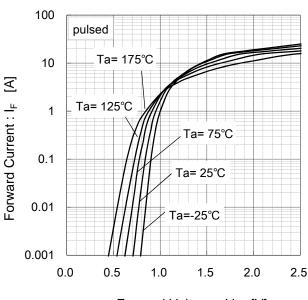
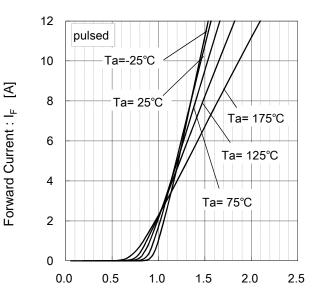
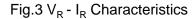


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V] Forward Voltage : V_F [V]



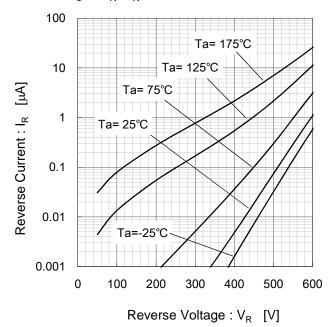
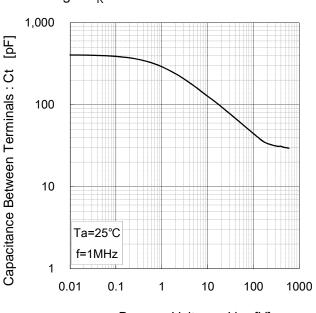


Fig.4 V_R-Ct Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

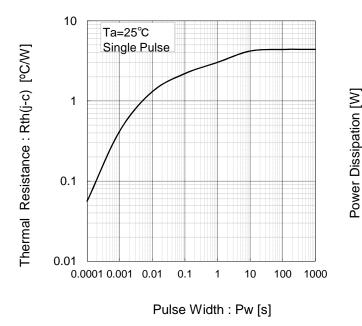
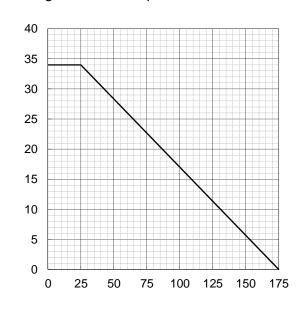


Fig.6 Power Dissipation



Case Temperature: Tc [°C]

Fig.7 Derating Curve Ip-Tc

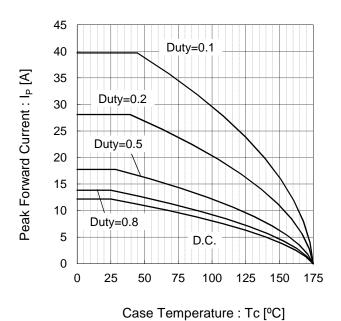
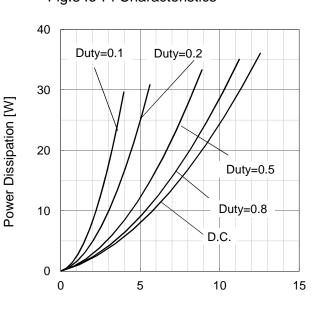


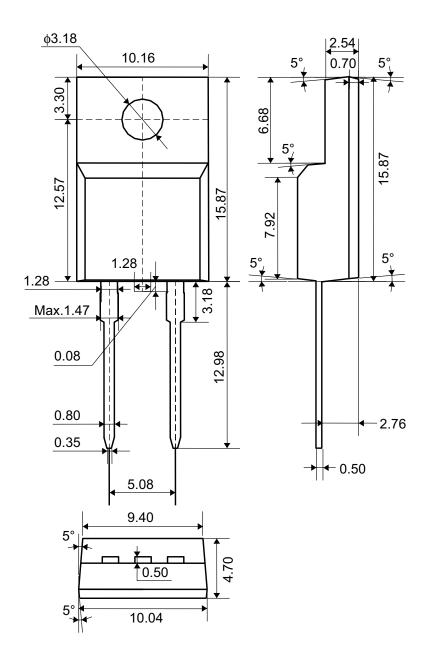
Fig.8 Io-Pf Characteristics



Average Rectified Forward Current : Io [A]

●Dimensions (Unit : mm)

TO-220FM (2pin)



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